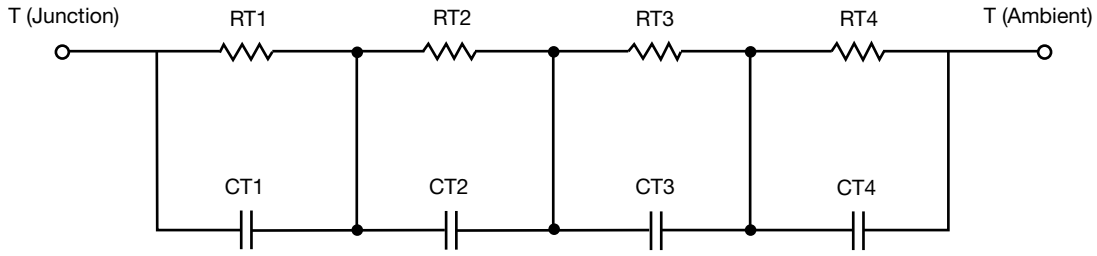
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, “Thermal Simulation of Power MOSFETs on the P-SPICE Platform”.

R-C THERMAL MODEL FOR TANK CONFIGURATION



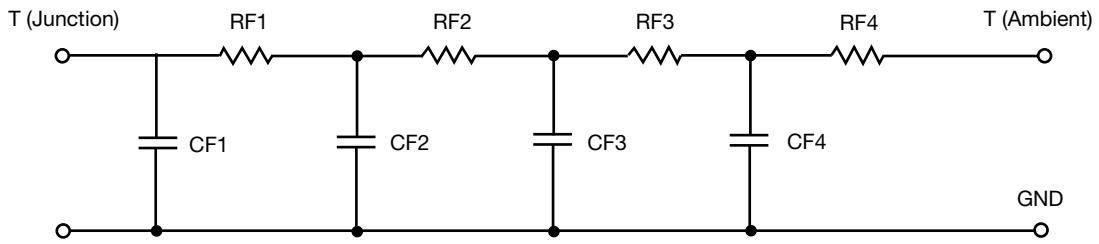
R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	**Ambient**	**Case**	**Foot**
RT1	12.5953	1.1486	N/A
RT2	4.9120	1.6922	N/A
RT3	13.8186	428.3096m	N/A
RT4	38.8639	727.3022m	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	**Ambient**	**Case**	**Foot**
CT1	2.0409	4.1412m	N/A
CT2	1.7785m	21.7503m	N/A
CT3	58.7049m	730.8424u	N/A
CT4	1.9880	121.9035m	N/A

Note

- n/a indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION



R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	**Ambient**	**Case**	**Foot**
RF1	5.9804	1.1973	N/A
RF2	7.6915	1.6502	N/A
RF3	10.6180	837.9780m	N/A
RF4	45.6079	308.0003m	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	**Ambient**	**Case**	**Foot**
CF1	2.5051m	951.0750u	N/A
CF2	49.9288m	8.5964m	N/A
CF3	112.9529m	28.8165m	N/A
CF4	1.2381	80.3674u	N/A

Note

- n/a indicates not applicable